

General Description

The WSR18P10 is the highest performance trench P-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the small power switching and load switch applications.

The WSR18P10 meet the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent Cdv/dt effect decline
- Green Device Available

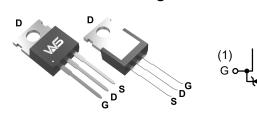
Product Summery

B _{VDSS}	R _{DSON}	I _D		
-100V	80mΩ	-25A		

Applications

- High Frequency Point-of-Load Synchronous
 Small power switching for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- ESD:3KV

TO-220-3L Pin Configuration



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-100	V
V_{GS}	Gate-Source Voltage	±20	V
I _D @T _c =25℃	Continuous Drain Current, V _{GS} @ -10V ¹	-25	Α
I _D @T _c =70°C	Continuous Drain Current, V _{GS} @ -10V ¹	-15	Α
I _{DM}	Pulsed Drain Current ²	-80	Α
P _D @T _c =25℃	Total Power Dissipation ³	89	W
T _{STG}	Storage Temperature Range	-55 to 150	$^{\circ}$
TJ	Operating Junction Temperature Range	-55 to 150	℃

Thermal Data

Symbol	Parameter	Тур.	Max.	Unit
R _{0JA}	Thermal Resistance Junction-ambient ¹		62	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case ¹		1.4	°C/W



Electrical Characteristics (T_J=25 ℃, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} =0V , I_D =-250uA	-100			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BVDSS Temperature Coefficient	Reference to 25°C , I _D =-1mA		-0.0624		V/℃	
В	Static Drain-Source On-Resistance ²	V _{GS} =-10V , I _D =-1A		80	100	mΩ	
$R_{DS(ON)}$		V_{GS} =-4.5V , I_D =-0.5A		100	115		
$V_{GS(th)}$	Gate Threshold Voltage	V _{GS} =V _{DS} . In =-250uA	-1.0	-1.5	-3.5	V	
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient	──V _{GS} −V _{DS} , I _D −-250uA		4.5		mV/℃	
	Drain Source Leakage Current	V_{DS} =-80V , V_{GS} =0V , T_J =25 $^{\circ}$ C			10	uA	
I _{DSS}	Drain-Source Leakage Current	V_{DS} =-80V , V_{GS} =0V , T_J =55 $^{\circ}$ C			100	uA	
I _{GSS}	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA	
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-1A		23		S	
Rg	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz		16	32	Ω	
Q_g	Total Gate Charge (-10V)			50			
Q_{gs}	Gate-Source Charge	V_{DS} =-50V , V_{GS} =-10V , I_{D} =-1A		7.5		nC	
Q_gd	Gate-Drain Charge			16.5			
$T_{d(on)}$	Turn-On Delay Time			12			
T _r	Rise Time	V_{DD} =-50V , V_{GS} =-10V , R_G =3.3 Ω		33		no	
T _{d(off)}	Turn-Off Delay Time	I _D =-0.5A		61		ns	
T _f	Fall Time			78		1	
Ciss	Input Capacitance			2580			
C _{oss}	Output Capacitance	V _{DS} =-25V , V _{GS} =0V , f=1MHz		185		pF	
C _{rss}	Reverse Transfer Capacitance			140			

Diode Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current ^{1,4}	V -V -0V Force Current			-25	Α
I _{SM}	Pulsed Source Current ^{2,4}	V _G =V _D =0V , Force Current			-80	Α
V _{SD}	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25℃			-1.3	V
t _{rr}	Reverse Recovery Time			53		nS
Q _{rr}	Reverse Recovery Charge	IF=-1A,dI/dt=100A/µs,T _J =25℃		125		nC

Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, t<10 sec.
- 2.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3. The power dissipation is limited by 150 °C junction temperature
- $\textbf{4.The data is theoretically the same as } I_D \text{ and } I_{DM} \text{ , in real applications , should be limited by total power dissipation.}$



Typical Characteristics

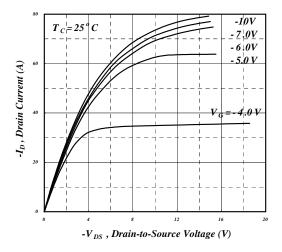


Fig 1. Typical Output Characteristics

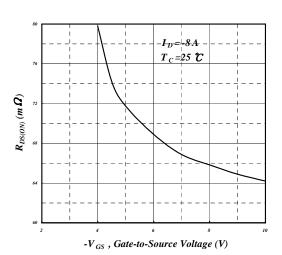


Fig 3. On-Resistance v.s. Gate Voltage

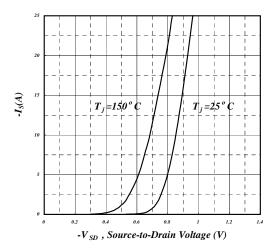


Fig 5. Forward Characteristic of Reverse Diode

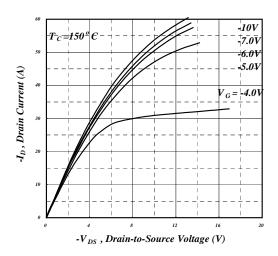


Fig 2. Typical Output Characteristics

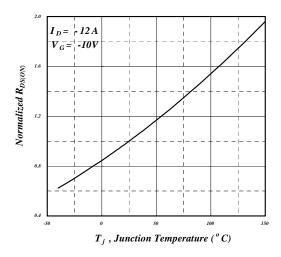


Fig 4. Normalized On-Resistance v.s. Junction Temperature

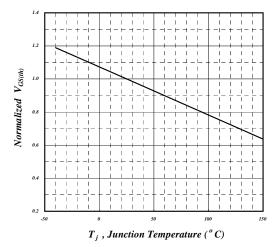


Fig 6. Gate Threshold Voltage v.s.
Junction Temperature



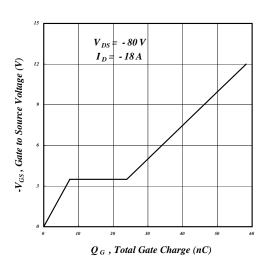


Fig 7. Gate Charge Characteristics

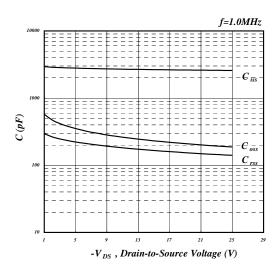


Fig 8. Typical Capacitance Characteristics

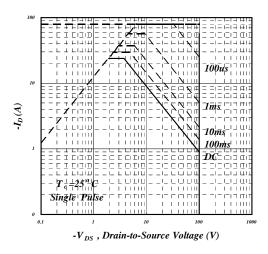


Fig 9. Maximum Safe Operating Area

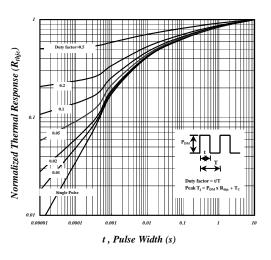


Fig 10. Effective Transient Thermal Impedance

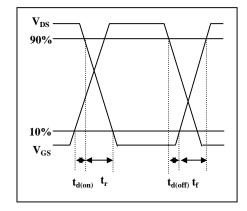


Fig 11. Switching Time Waveform

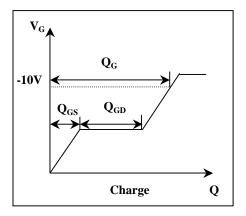
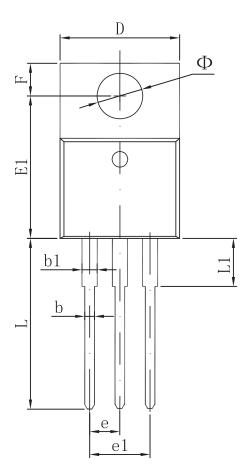
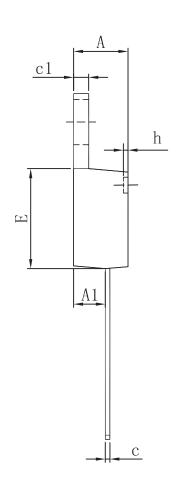


Fig 12. Gate Charge Waveform



Packaging information





Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	4.470	4.670	0.176	0.184	
A1	2.520	2.820	0.099	0.111	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
Е	8. 500	8.900	0.335	0.350	
E1	12.060	12.460	0.475	0.491	
е	2.540	O TYP	0.100) TYP	
e1	4. 980	5. 180	0.196	0.204	
F	2.590	2.890	0.102	0.114	
h	0.000	0.300	0.000	0.012	
L	13.400	13.800	0.528	0.543	
L1	3.560	3.960	0.140	0.156	
Ф	3.735	3. 935	0.147	0.155	



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